

0039-7271-2SRD



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2/26/03
Adm H

IN THE UNITED STATES PATENT & TRADEMARK OFFICE

IN RE APPLICATION OF :
DAISABURO TAKASHIMA ET AL : EXAMINER: DICKEY, T. L.
SERIAL NO: 09/340,720 :
RCE FILED: SEPTEMBER 6, 2002 : GROUP ART UNIT: 2826
FOR: SEMICONDUCTOR DEVICE

RECEIVED
FEB 21 2003
TC 2800 MAIL ROOM

AMENDMENT

ASSISTANT COMMISSIONER FOR PATENTS
WASHINGTON, D.C. 20231

SIR:

In response to the Official Action mailed November 18, 2002, please amend this application as follows:

IN THE CLAIMS

Please amend Claims 1, 9 and 10 to read as follows:¹

1. (Three Times Amended) A semiconductor device comprising:
- a channel of a first conductivity type formed on a surface layer of a semiconductor substrate;
- a source and a drain of a second conductivity type formed on both sides of the channel;

¹A marked-up copy of the changes made to the claims is attached.